

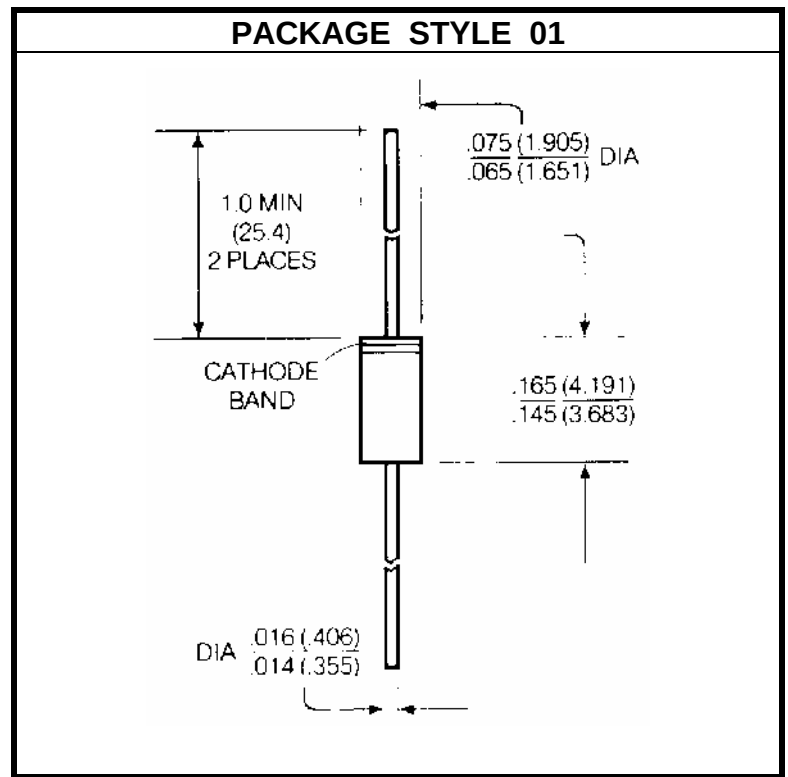
SILICON PIN DIODE

DESCRIPTION:

The **ASI 5082-3077** is a Silicon PIN Diode Designed for General Purpose Attenuator and Switching Applications from 100 MHz to 3 GHz.

MAXIMUM RATINGS

I_F	100 mA
V_R	200 V
P_{DISS}	250 mW @ $T_A = 25\text{ }^{\circ}\text{C}$
T_J	-65 $^{\circ}\text{C}$ to +200 $^{\circ}\text{C}$
T_{STG}	-65 $^{\circ}\text{C}$ to +200 $^{\circ}\text{C}$
θ_{JC}	0.7 $^{\circ}\text{C}/\text{mW}$



CHARACTERISTICS $T_C = 25\text{ }^{\circ}\text{C}$

SYMBOL	TEST CONDITIONS		MINIMUM	TYPICAL	MAXIMUM	UNITS
V_{BR}	$I_R = 10\text{ }\mu\text{A}$		200			V
C_T	$V_R = 850\text{ V}$	$f = 1.0\text{ MHz}$			0.3	pF
R_S	$I_F = 100\text{ mA}$	$f = 100\text{ MHz}$			1.5	Ω
τ	$I_F = 50\text{ mA}$	$I_R = 250\text{ mA}$	100			μS
t_{rr}	$V_R = 10\text{ V}$	$f = 20\text{ mA}$		100		μS